



DMT3006LFG

PowerDI3333-8

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C
	6mΩ @ V <sub>GS</sub> = 10V	
30V	10mΩ @ V <sub>GS</sub> = 4.5V	55.6A

**Description and Applications** 

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$ , yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

# **Features and Benefits**

- Low R<sub>DS(ON)</sub> Ensures On-State Losses are Minimized
- Excellent Q<sub>GD</sub> × R<sub>DS(ON)</sub> Product (FOM)
- Advanced Technology for DC-DC Converters
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products

N-CHANNEL ENHANCEMENT MODE MOSFET

- Occupies Just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- 100% UIS (Avalanche) Rated
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

# **Mechanical Data**

1

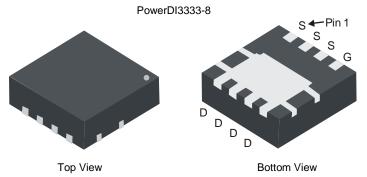
2

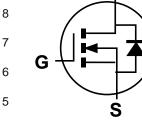
3

4

- Case: PowerDI<sup>®</sup>3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.072 grams (Approximate)

Top View





Equivalent Circuit

D

### Ordering Information (Note 4)

	-	
Part Number	Case	Packaging
DMT3006LFG-7	PowerDI3333-8	2,000/Tape & Reel
DMT3006LFG-13	PowerDI3333-8	3,000/Tape & Reel

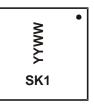
Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



SK1 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)



#### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	30	V	
Gate-Source Voltage	V <sub>GSS</sub>	±20	V	
Continuous Drain Current (Note 6) $V_{GS}$ = 10V	T <sub>C</sub> = +25°C T <sub>C</sub> = +70°C	ID	55.6 44.4	А
Continuous Drain Current (Note 5) $V_{GS}$ = 10V	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	16.0 12.8	A
Maximum Continuous Body Diode Forward Current (Note 5)	Is	2	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	80	А	
Avalanche Current, L=0.1mH	I <sub>AS</sub>	25	А	
Avalanche Energy, L=0.1mH	E <sub>AS</sub>	31	mJ	

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Total Power Dissipation (Note 6)	T <sub>C</sub> = +25°C	PD	27.8	W	
Thermal Resistance, Junction to Case (Note 6)		R <sub>θJC</sub>	4.5	°C/W	
Thermal Resistance, Junction to Ambient (Note 5)		R <sub>0JA</sub>	54	C/W	
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C	

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	_	_	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	—	—	1	μA	$V_{DS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = +20V, V_{DS} = 0V$ $V_{GS} = -16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.0	—	3.0	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance			4.8	6	mΩ	$V_{GS} = 10V, I_D = 12A$	
	R <sub>DS(ON)</sub>	_	6.9	10		$V_{GS} = 4.5V, I_D = 12A$	
Diode Forward Voltage	V <sub>SD</sub>	_	0.7	1.0	V	$V_{GS} = 0V, I_{S} = 2A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		1,155	—	pF	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Output Capacitance	Coss	_	456	—			
Reverse Transfer Capacitance	Crss	_	72	—			
Gate Resistance	R <sub>G</sub>	—	1.6	—	Ω	V <sub>DS</sub> = 0V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	$Q_{G}$	_	8.4	—		V <sub>DD</sub> = 15V, I <sub>D</sub> = 9A	
Total Gate Charge (V <sub>GS</sub> = 10V)	Q <sub>G</sub>	—	16.7	—	nC		
Gate-Source Charge	Q <sub>GS</sub>	_	2.2	—	nc		
Gate-Drain Charge	Q <sub>GD</sub>	_	3.5	_			
Turn-On Delay Time	t <sub>D(ON)</sub>		3.5	—		$V_{DD}$ = 15V, $V_{GS}$ = 10V, $R_G$ = 3 $\Omega$ , $I_D$ = 9A	
Turn-On Rise Time	t <sub>R</sub>	_	5.5	_			
Turn-Off Delay Time	t <sub>D(OFF)</sub>		13.5	—	ns		
Turn-Off Fall Time	tF		4.6	—			
Body Diode Reverse Recovery Time	t <sub>RR</sub>		19.3	—	ns		
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	-	8.6	—	nC	I <sub>F</sub> = 1.5A, di/dt = 100A/μs	

5. R<sub>0</sub>JA is determined with the device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate. R<sub>0</sub>JC is guaranteed by design while R<sub>0</sub>JA is determined by the user's board design.

6. Thermal resistance from junction to soldering point (on the exposed drain pad).

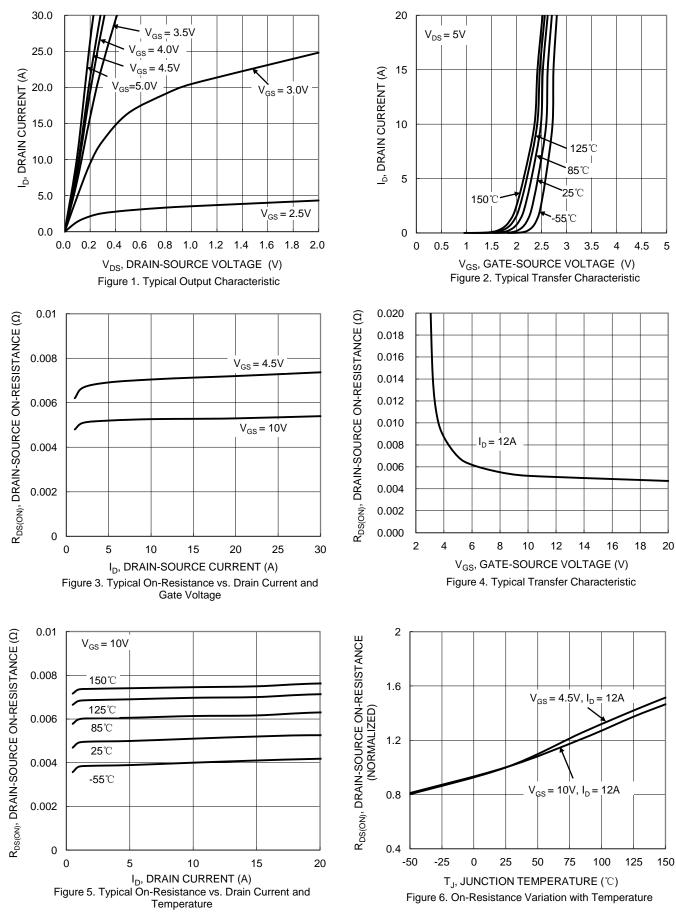
7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

Notes:

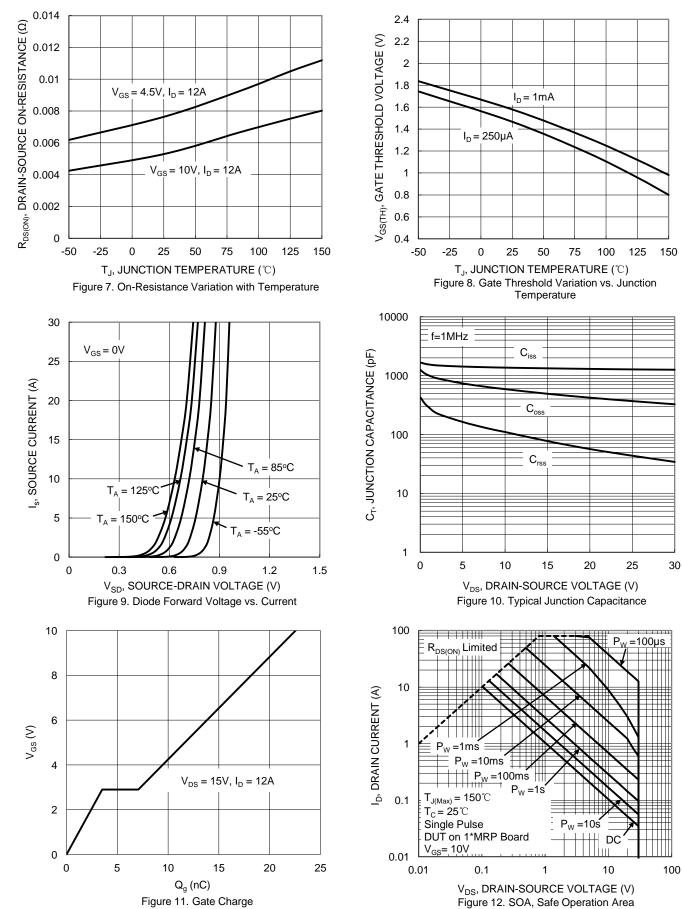


### DMT3006LFG



DMT3006LFG Document number: DS38252 Rev. 5 - 2 3 of 7 www.diodes.com September 2018 © Diodes Incorporated





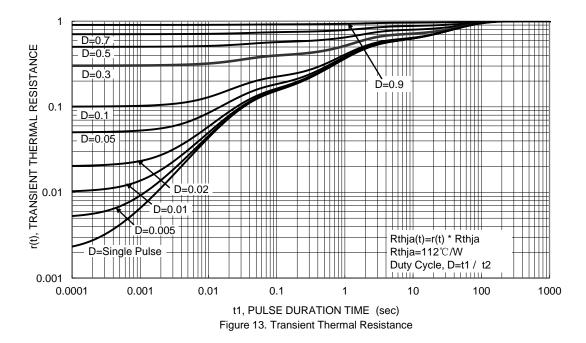
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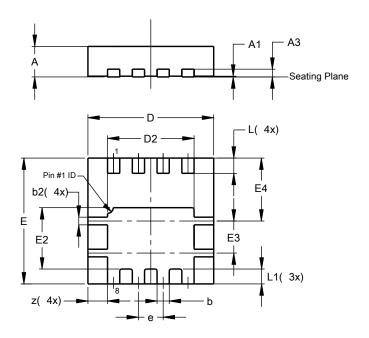






# **Package Outline Dimensions**

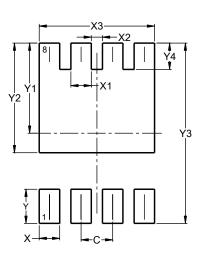
Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI3333-8						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	0.02			
A3	_	_	0.203			
b	0.27	0.37	0.32			
b2	0.15	0.25	0.20			
D	3.25	3.35	3.30			
D2	2.22	2.32	2.27			
Е	3.25	3.35	3.30			
E2	1.56	1.66	1.61			
E3	0.79	0.89	0.84			
E4	1.60	1.70	1.65			
е	-	-	0.65			
L	0.35	0.45	0.40			
L1	_	-	0.39			
z	_	_	0.515			
All Dimensions in mm						

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



#### PowerDI3333-8

PowerDI3333-8

Dimensions	Value (in mm)		
С	0.650		
Х	0.420		
X1	0.420		
X2	0.230		
X3	2.370		
Y	0.700		
Y1	1.850		
Y2	2.250		
Y3	3.700		
Y4	0.540		



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